

# RJK03E6DPA

30V, 35A, 4.6mΩ max.

Built in SBD N Channel Power MOS FET

High Speed Power Switching

R07DS0947EJ0400

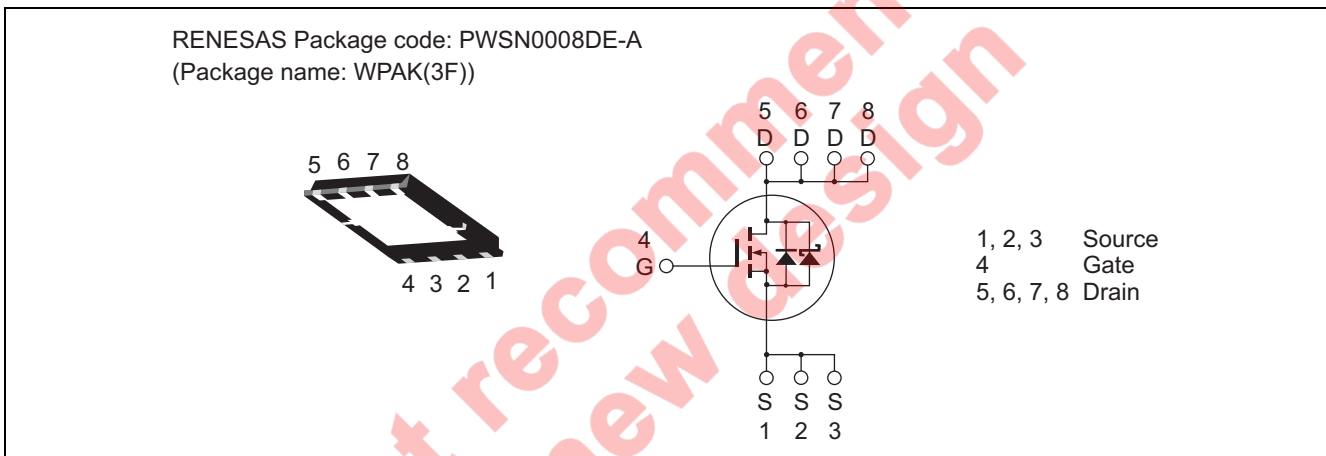
Rev.4.00

Mar 22, 2013

## Features

- High speed switching
- Capable of 4.5 V gate drive
- Low drive current
- High density mounting
- Low on-resistance
- Pb-free
- Halogen-free

## Outline



## Absolute Maximum Ratings

(Ta = 25°C)

Item	Symbol	Ratings	Unit
Drain to source voltage	V <sub>DSS</sub>	30	V
Gate to source voltage	V <sub>GSS</sub>	±12	V
Drain current	I <sub>D</sub>	35	A
Drain peak current	I <sub>D(pulse)</sub> <sup>Note1</sup>	140	A
Body-drain diode reverse drain current	I <sub>DR</sub>	35	A
Avalanche current	I <sub>AP</sub> <sup>Note 2</sup>	13	A
Avalanche energy	E <sub>AR</sub> <sup>Note 2</sup>	16.9	mJ
Channel dissipation	P <sub>ch</sub> <sup>Note3</sup>	35	W
Channel to case thermal impedance	θ <sub>ch-c</sub> <sup>Note3</sup>	3.57	°C/W
Channel temperature	T <sub>ch</sub>	150	°C
Storage temperature	T <sub>stg</sub>	-55 to +150	°C

- Notes: 1. PW ≤ 10 μs, duty cycle ≤ 1%  
 2. Value at T<sub>ch</sub> = 25°C, R<sub>g</sub> ≥ 50 Ω  
 3. T<sub>c</sub> = 25°C

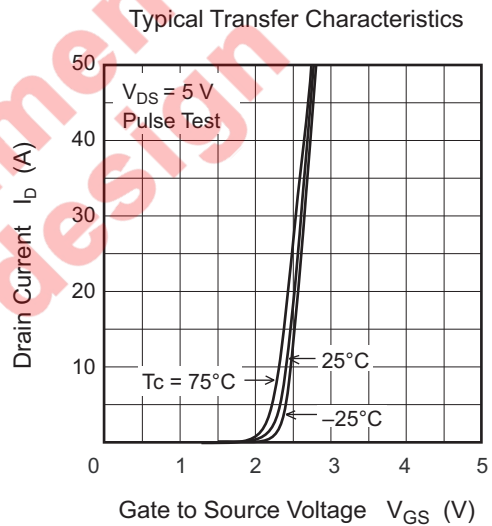
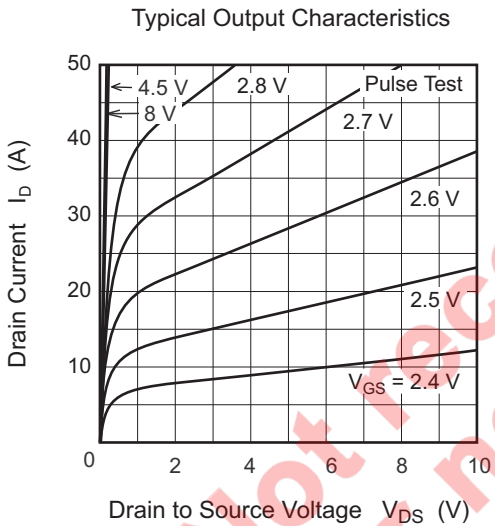
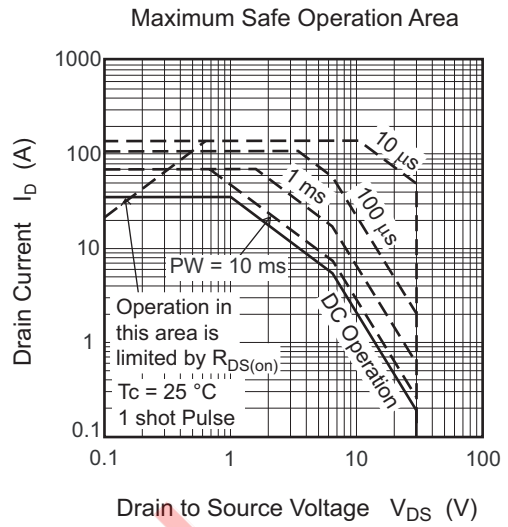
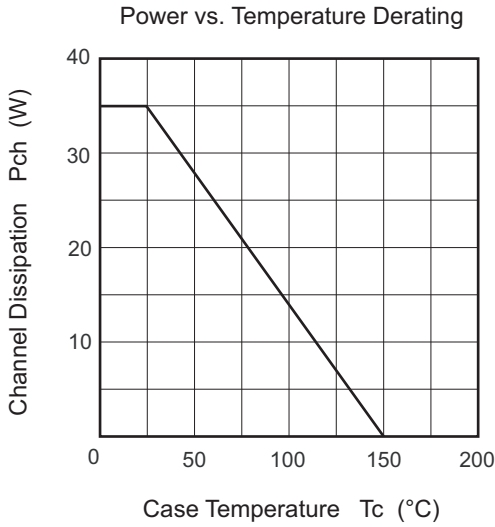
## Electrical Characteristics

(Ta = 25°C)

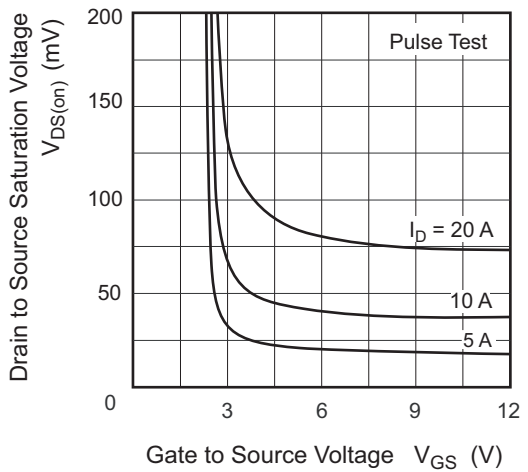
Item	Symbol	Min	Typ	Max	Unit	Test Conditions
Drain to source breakdown voltage	$V_{(BR)DSS}$	30	—	—	V	$I_D = 10 \text{ mA}$ , $V_{GS} = 0$
Gate to source leak current	$I_{GSS}$	—	—	$\pm 0.1$	$\mu\text{A}$	$V_{GS} = \pm 12 \text{ V}$ , $V_{DS} = 0$
Zero gate voltage drain current	$I_{DSS}$	—	—	1	mA	$V_{DS} = 30 \text{ V}$ , $V_{GS} = 0$
Gate to source cutoff voltage	$V_{GS(off)}$	1.2	—	2.5	V	$V_{DS} = 10 \text{ V}$ , $I_D = 1 \text{ mA}$
Static drain to source on state resistance	$R_{DS(on)}$	—	3.8	4.6	$\text{m}\Omega$	$I_D = 17.5\text{A}$ , $V_{GS} = 8.0 \text{ V}$ <sup>Note4</sup>
	$R_{DS(on)}$	—	4.6	5.6	$\text{m}\Omega$	$I_D = 17.5\text{A}$ , $V_{GS} = 4.5 \text{ V}$ <sup>Note4</sup>
Forward transfer admittance	$ y_{fs} $	—	83	—	S	$I_D = 17.5\text{A}$ , $V_{DS} = 5 \text{ V}$ <sup>Note4</sup>
Input capacitance	$C_{iss}$	—	2670	3740	pF	$V_{DS} = 10 \text{ V}$
Output capacitance	$C_{oss}$	—	320	—	pF	$V_{GS} = 0$
Reverse transfer capacitance	$C_{rss}$	—	200	—	pF	$f = 1 \text{ MHz}$
Gate Resistance	$R_g$	—	1.7	3.4	$\Omega$	
Total gate charge	$Q_g$	—	20	—	nC	$V_{DD} = 10 \text{ V}$
Gate to source charge	$Q_{gs}$	—	7	—	nC	$V_{GS} = 4.5 \text{ V}$
Gate to drain charge	$Q_{gd}$	—	6.2	—	nC	$I_D = 35 \text{ A}$
Turn-on delay time	$t_{d(on)}$	—	14	—	ns	$V_{GS} = 8 \text{ V}$ , $I_D = 17.5 \text{ A}$
Rise time	$t_r$	—	5.4	—	ns	$V_{DD} \cong 10 \text{ V}$
Turn-off delay time	$t_{d(off)}$	—	52	—	ns	$R_L = 0.57 \Omega$
Fall time	$t_f$	—	8	—	ns	$R_g = 4.7 \Omega$
Body-drain diode forward voltage	$V_{DF}$	—	0.39	—	V	$I_F = 2 \text{ A}$ , $V_{GS} = 0$ <sup>Note4</sup>
Body-drain diode reverse recovery time	$t_{rr}$	—	24	—	ns	$I_F = 35 \text{ A}$ , $V_{GS} = 0$ $di_F/dt = 100 \text{ A}/\mu\text{s}$

Notes: 4. Pulse test

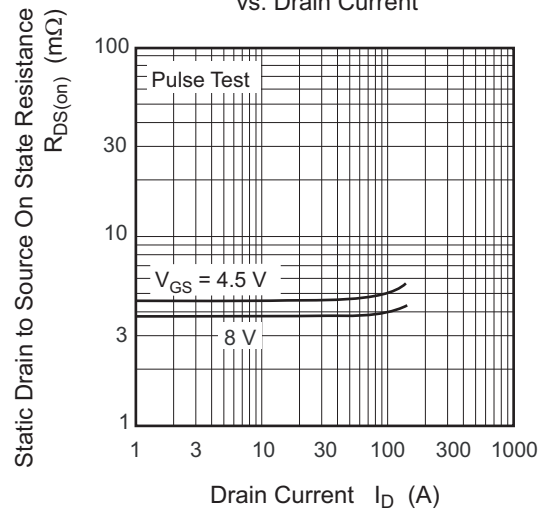
Main Characteristics

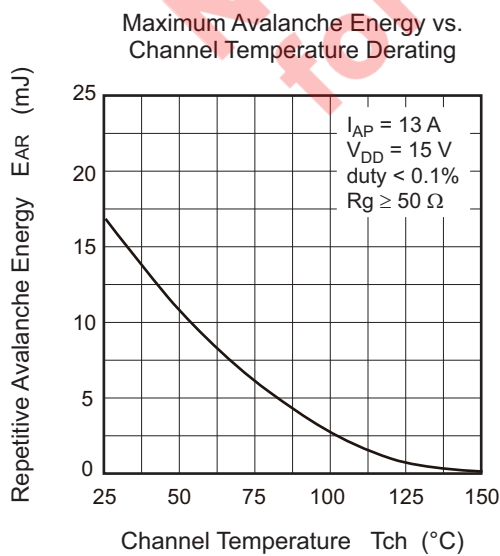
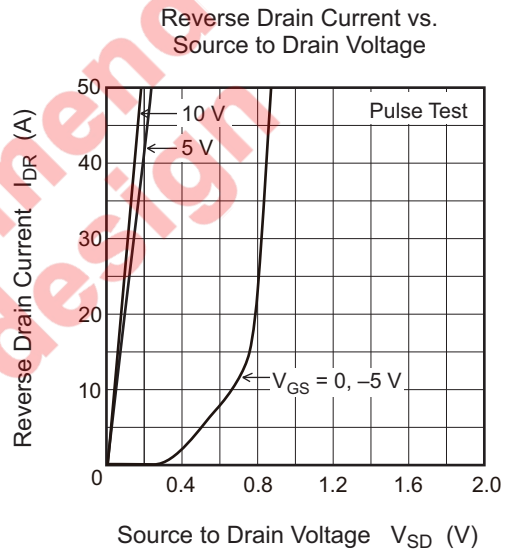
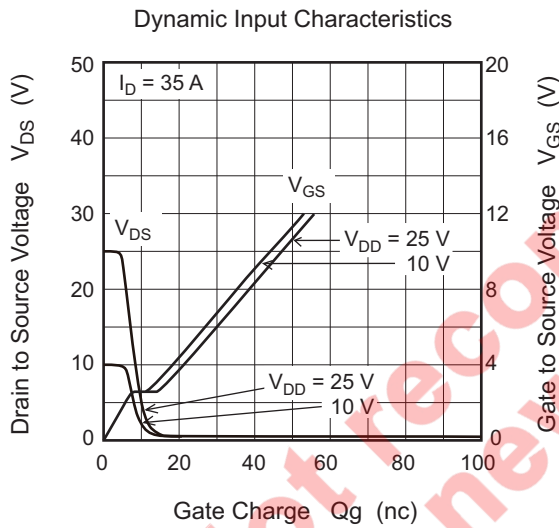
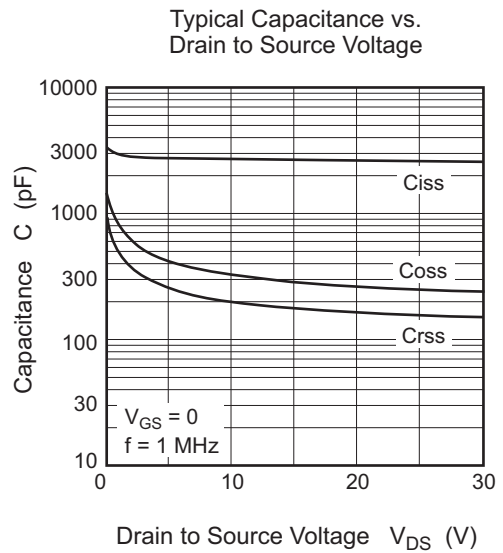
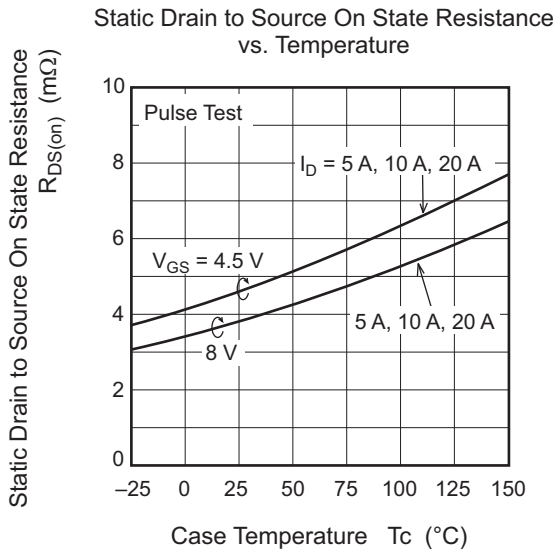


Drain to Source Saturation Voltage vs. Gate to Source Voltage

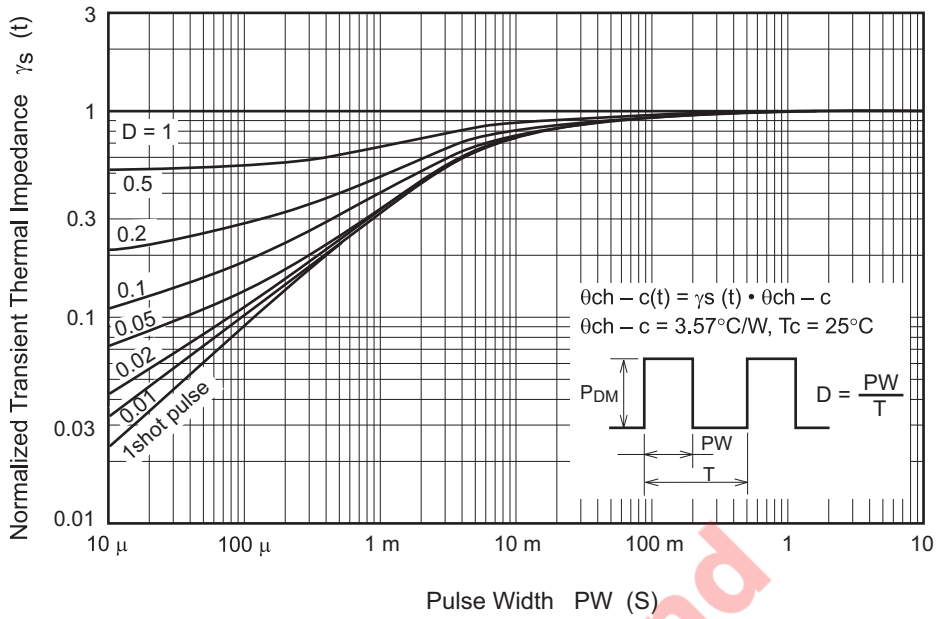


Static Drain to Source On State Resistance vs. Drain Current

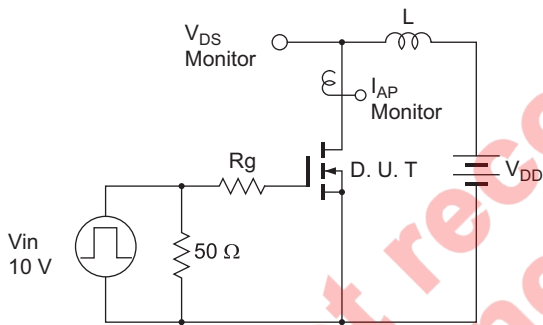




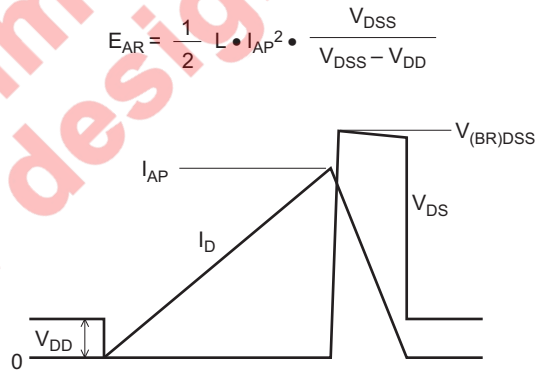
Normalized Transient Thermal Impedance vs. Pulse Width



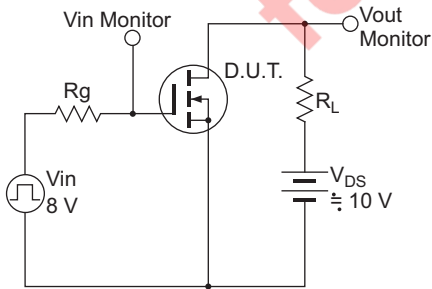
Avalanche Test Circuit



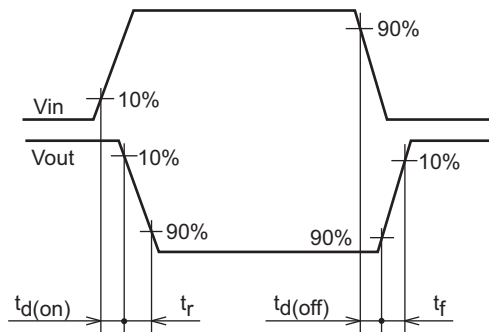
Avalanche Waveform



Switching Time Test Circuit



Switching Time Waveform



### Package Dimensions



### Ordering Information

Orderable Part Number	Quantity	Shipping Container
RJK03E6DPA-00-J5A	3000 pcs	Taping

Note: The symbol of 2nd "-" is occasionally presented as "#".

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